Common-mode EMI filter for differential channels with integrated ESD protection

Rev. 2 — 28 April 2014

**Product data sheet** 

## 1. Product profile

#### 1.1 General description

The devices are common-mode ElectroMagnetic Interference (EMI) filters with integrated ElectroStatic Discharge (ESD) protection for two and three differential channels. The devices are designed to provide low insertion loss for differential high-speed signals on each channel while unwanted common-mode signals are attenuated.

Each differential channel incorporates two signal lines that are coupled by integrated coils. Diodes provide protection to downstream components from ESD voltages up to  $\pm 15$  kV on each signal line.

Table 1. Product overview

| Type number | Number of | Package    |           |        |  |  |
|-------------|-----------|------------|-----------|--------|--|--|
|             | channels  | Name       | Version   |        |  |  |
| PCMF2DFN1   | 2         | DFN2520-9  | SOT1333-1 | XSON9  |  |  |
| PCMF3DFN1   | 3         | DFN4020-14 | SOT1334-1 | XSON14 |  |  |

#### 1.2 Features and benefits

- Two and three differential channels common-mode EMI filter with integrated ESD protection
- Superior common-mode suppression over a wide frequency range
- ESD protection up to ±15 kV contact discharge according to IEC 61000-4-2
- Maximum package height: 0.5 mm

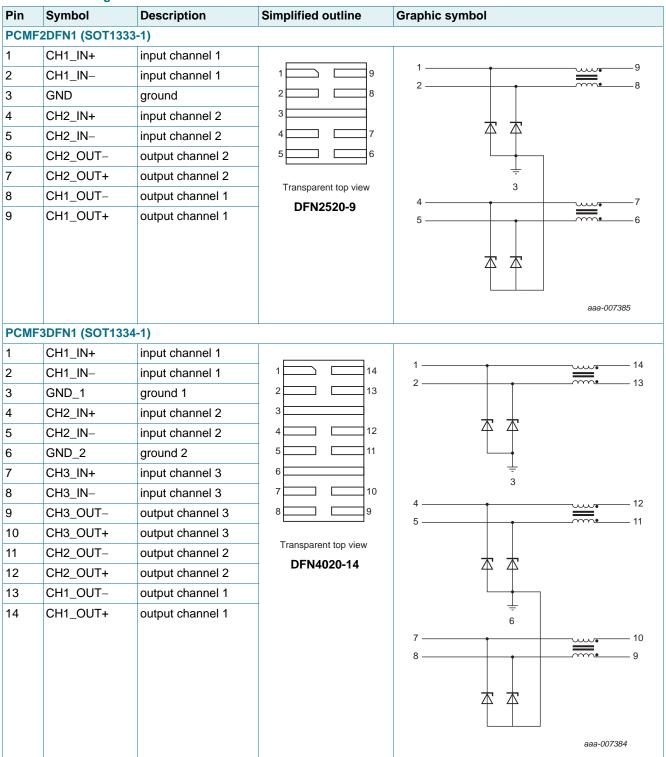
### 1.3 Applications

- Smartphone, cellular and cordless phone
- MIPI D-PHY as used in Camera Serial Interface (CSI) and Display Serial Interface (DSI)
- General-purpose EMI and Radio-Frequency Interference (RFI) filter and downstream ESD protection
- Tablet PC and Mobile Internet Device (MID)
- High-Definition Multimedia Interface (HDMI)



## 2. Pinning information

Table 2. Pinning



# 3. Ordering information

Table 3. Ordering information

| Type number | Package    |  |           |  |  |
|-------------|------------|--|-----------|--|--|
|             | Name       | Description  | Version   |  |  |
| PCMF2DFN1   | DFN2520-9  | plastic extremely thin small outline package; no leads; 9 terminals; body $2 \times 2.5 \times 0.5$ mm | SOT1333-1 |  |  |
| PCMF3DFN1   | DFN4020-14 | plastic extremely thin small outline package; no leads; 14 terminals; body $2 \times 4 \times 0.5$ mm  | SOT1334-1 |  |  |

## 4. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| PCMF2DFN1   | MP1          |
| PCMF3DFN1   | CMFMP1       |

# 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter   | Conditions                                       | Min  | Max  | Unit |
|------------------|---|--|------|------|------|
| VI               | input voltage                                     |  | -0.5 | 5    | V    |
| V <sub>ESD</sub> | electrostatic discharge voltage                   | IEC 61000-4-2, level 4; all input pins to ground |      |      |      |
|                  |   | contact discharge                                | -15  | 15   | kV   |
|                  |   | air discharge                                    | -15  | 15   | kV   |
|                  | IEC 61000-4-2, level 4; all output pins to ground |  |      |      |      |
|                  |   | contact discharge                                | -2   | 2    | kV   |
|                  |   | air discharge                                    | -2   | 2    | kV   |
| T <sub>stg</sub> | storage temperature                               |  | -55  | +125 | °C   |
| T <sub>amb</sub> | ambient temperature                               |  | -40  | +85  | °C   |

## 6. Characteristics

#### 6.1 Channel characteristics

Table 6. Channel characteristics

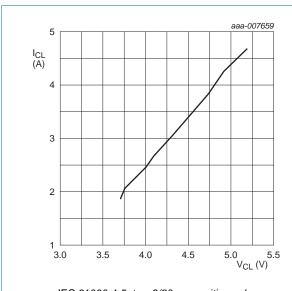
 $T_{amb} = 25$  °C unless otherwise specified.

| Symbol             | Parameter                  | Conditions                                      | Min | Тур   | Max  | Unit |
|--------------------|----------------------------|---|-----|-------|------|------|
| R <sub>s(ch)</sub> | channel series resistance  | single line; input to output                    |     | 5     | -    | Ω    |
| C <sub>d</sub>     | diode capacitance          | f = 1 MHz; V <sub>I</sub> = 2.5 V               | -   | 0.6   | 0.75 | pF   |
| I <sub>RM</sub>    | reverse leakage<br>current | per line; V <sub>I</sub> = 5 V                  | -   | -     | 100  | nA   |
| $V_{BR}$           | breakdown voltage          | I <sub>R</sub> = 10 mA                          | 6   | -     | 9    | V    |
| V <sub>F</sub>     | forward voltage            | I <sub>F</sub> = 10 mA                          | 0.6 | -     | 1.1  | V    |
| R <sub>dyn</sub>   | dynamic resistance         | TLP [2]   |     |       |      |      |
|                    |                            | positive transient                              | -   | 0.6   | -    | Ω    |
|                    |                            | negative transient                              | -   | 0.6   | -    | Ω    |
|                    |                            | surge [3]                                       |     |       |      |      |
|                    |                            | positive transient                              | -   | 0.6   | -    | Ω    |
|                    |                            | negative transient                              | -   | 0.6   | -    | Ω    |
| V <sub>CL</sub>    | clamping voltage           | positive transient; I <sub>PP</sub> = 4 A [3]   | -   | 4.8   | -    | V    |
|                    |                            | negative transient; $I_{PP} = -5 \text{ A}$ [3] | -   | -3.6  | -    | V    |
|                    |                            | TLP; I <sub>CL</sub> = 8 A                      | -   | 8     | -    | V    |
|                    |                            | TLP; I <sub>CL</sub> = 12 A                     | -   | 10.5  | -    | V    |
|                    |                            | TLP; I <sub>CL</sub> = 16 A                     | -   | 13.4  | -    | V    |
|                    |                            | TLP; $I_{CL} = -8 A$                            | -   | -6    | -    | V    |
|                    |                            | TLP; I <sub>CL</sub> = -12 A                    | -   | -8.4  | -    | V    |
|                    |                            | TLP; I <sub>CL</sub> = -16 A                    | -   | -10.7 | -    | V    |

<sup>[1]</sup> This parameter is guaranteed by design.

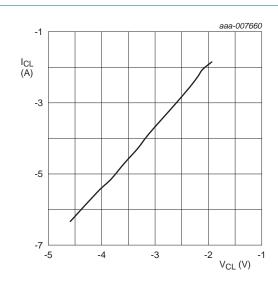
<sup>[2] 100</sup> ns Transmission Line Pulse (TLP); 50  $\Omega$ ; pulser at 70 to 90 ns.

<sup>[3]</sup> According to IEC 61000-4-5 (8/20  $\mu$ s).



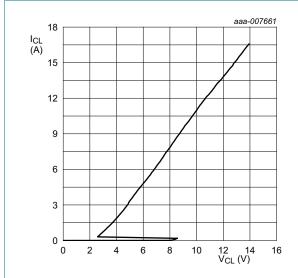
IEC 61000-4-5;  $t_p$  = 8/20  $\mu$ s; positive pulse

Fig 1. Dynamic resistance with positive clamping; typical values



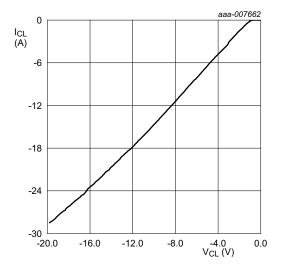
IEC 61000-4-5;  $t_p = 8/20 \mu s$ ; negative pulse

Fig 2. Dynamic resistance with negative clamping; typical values



t<sub>p</sub> = 100 ns; Transmission Line Pulse (TLP)

Fig 3. Dynamic resistance with positive clamping; typical values



t<sub>p</sub> = 100 ns; Transmission Line Pulse (TLP)

Fig 4. Dynamic resistance with negative clamping; typical values

The device uses an advanced clamping structure showing a negative dynamic resistance. This snap-back behavior strongly reduces the clamping voltage to the system behind the ESD protection during an ESD event. Do not connect unlimited DC current sources to the data lines to avoid keeping the ESD protection device in snap-back state after exceeding breakdown voltage (due to an ESD pulse for instance).

## 6.2 Frequency characteristics

Table 7. Frequency characteristics

| Symbol                       | Parameter                   | Conditions  |        |   | Тур | Max | Unit |
|------------------------------|-----------------------------|-------------|--------|---|-----|-----|------|
| Commor                       | mode: S <sub>21cc</sub>     |             |        |   |     |     |      |
| $\alpha_{il}$ insertion loss |                             |             | [1]    |   |     |     |      |
|                              |                             | f = 400 MHz |        | - | 15  | -   | dB   |
|                              |                             | f = 800 MHz |        | - | 30  | -   | dB   |
|                              |                             | f = 5 GHz   |        | - | 21  | -   | dB   |
| Different                    | ial mode: S <sub>21dd</sub> |             |        |   |     | '   |      |
| $\alpha_{il}$                | insertion loss              | f = 1MHz    | [1]    | - | 0.6 | -   | dB   |
| f_3dB                        | cut-off frequency           |             | [1][2] | - | 2.2 | -   | GHz  |

- [1] Measured with 4-port network analyzer;  $R_{gen}$  = 50  $\Omega$ ;  $R_{L}$  = 50  $\Omega$ .
- [2] Normalized to attenuation at 1 MHz.

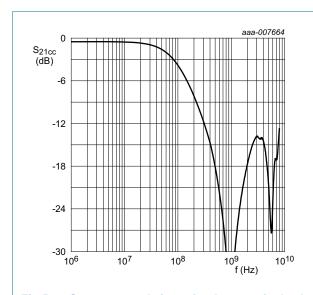


Fig 5. Common-mode insertion loss; typical values

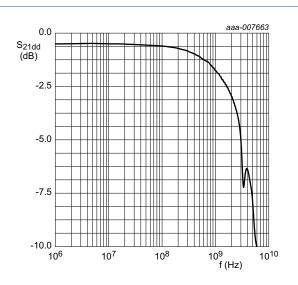
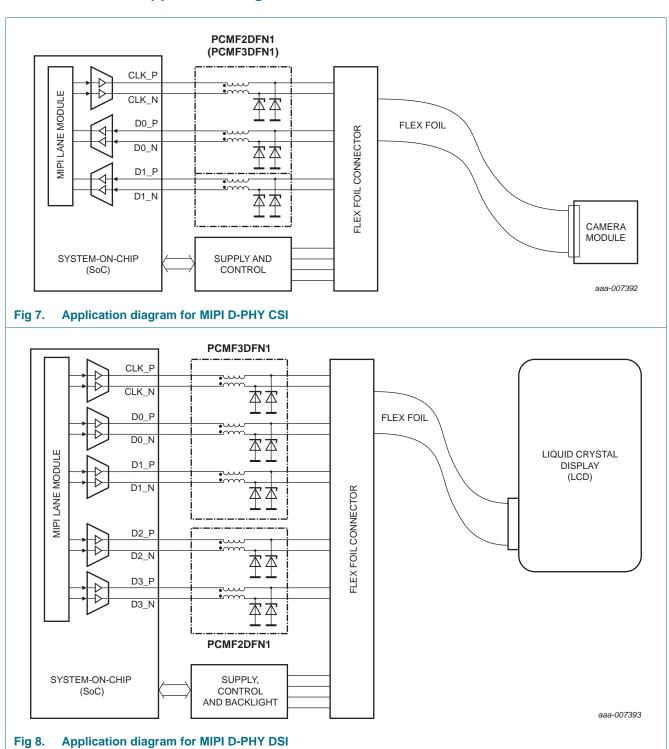


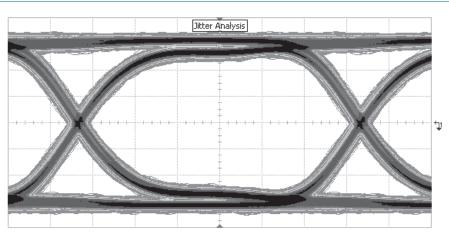
Fig 6. Differential-mode insertion loss; typical values

# 7. Application information

## 7.1 Application diagram



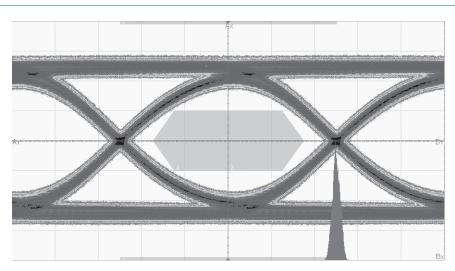
## 7.2 Eye diagram



aaa-007649

Data rate: 1.5 Gbit/s Vertical scale = 28.7 mV/div Horizontal scale = 100 ps/div

### Fig 9. MIPI D-PHY eye diagram



aaa-007648

Data rate: 3.4 Gbit/s Vertical scale = 200 mV/div Horizontal scale = 58.9 ps/div

Fig 10. HDMI eye diagram

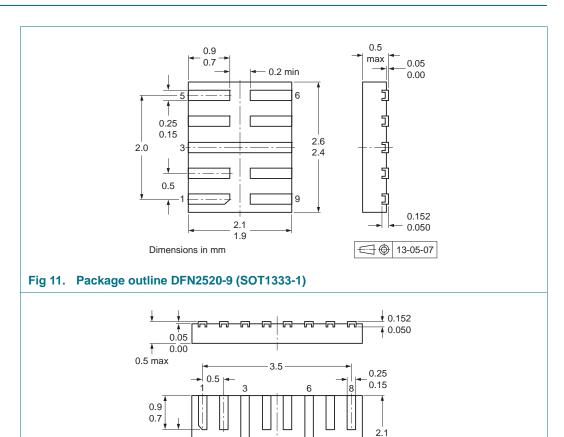
1.9

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9

Common-mode EMI filter for differential channels with ESD protection

# 8. Package outline



4.1

Fig 12. Package outline DFN4020-14 (SOT1334-1)

0.2

Dimensions in mm

14

## 9. Soldering

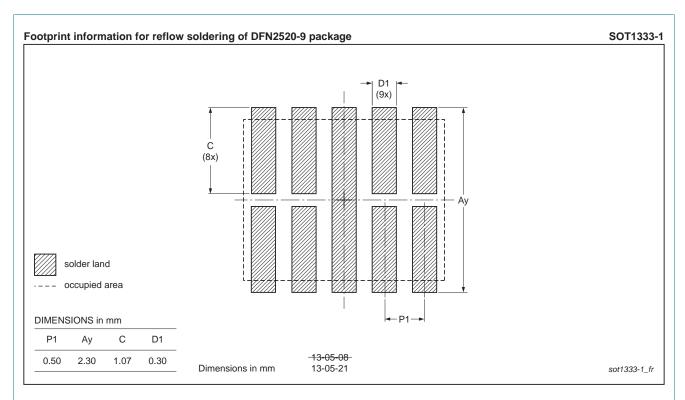
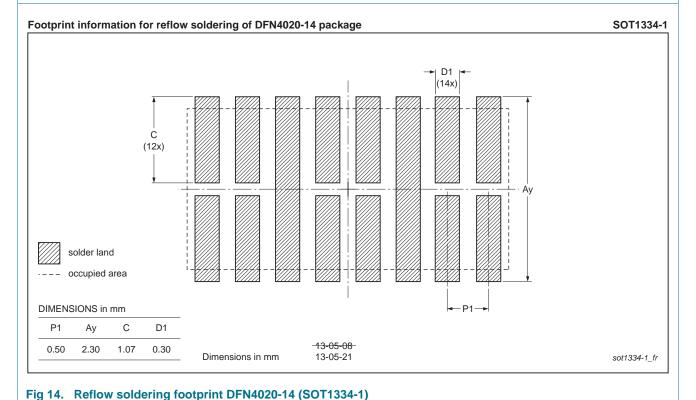


Fig 13. Reflow soldering footprint DFN2520-9 (SOT1333-1)



Common-mode EMI filter for differential channels with ESD protection

# 10. Revision history

#### Table 8. Revision history

| Document ID             | Release<br>date                |                    | Change notice | Supersedes              |
|-------------------------|--------------------------------|--------------------|---------------|-------------------------|
| PCMF2DFN1_PCMF3DFN1 v.2 | 20140428                       | Product data sheet | -             | PCMF2DFN1_PCMF3DFN1 v.1 |
| Modification:           | <ul> <li>Surge rati</li> </ul> | ng adapted         |               |                         |
| PCMF2DFN1_PCMF3DFN1 v.1 | 20130606                       | Product data sheet | -             | -                       |

#### Common-mode EMI filter for differential channels with ESD protection

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|--------------------------------|-------------------|---|
| Objective [short] data sheet   | Development       | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification     | This document contains data from the preliminary specification.                       |
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# PCMF2DFN1; PCMF3DFN1

## Common-mode EMI filter for differential channels with ESD protection

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